

September 2007

BC337A NPN Medium Power Transistor

- This device is designed for general purpose amplifier application at collector currents to 800m.
- Sourced from process 38.



Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	60	V
V _{CES}	Collector-Emitter Voltage	60	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	800	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ 150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

Thermal Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06".

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA	60			V
BV _{CES}	Collector-Emitter Cutoff Voltage	$I_{C} = 100 \mu A$	60			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 100 \mu A$	5			V
I _{EBO}	Emitter Cut-off Current	V _{EB} = 5V			10	μΑ
I _{CBO}	Collector Cut-off Current	V _{CB} = 20V, T = 25 °C T = 150 °C			0.1 5	μА
h _{FE}	DC Current Gain	$V_{CE} = 1V, I_{C} = 100mA$ $V_{CE} = 1V, I_{C} = 500mA$	100 40	400		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$			0.7	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 5V$, $I_{C} = 2mA$			1.2	V

- Notes:

 1. These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

 2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

 3. These ratings are based on a maximum junction temperature of 150degrees C.

© 2007 Fairchild Semiconductor Corporation BC337A Rev. 1.0.0

www.fairchildsemi.com

¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.

²⁾ These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.





TRADEMARKS

The following are registered and unregistered trademarks and service marks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

Power247® **ACEx®** Green FPS™ SuperSOT™-8 Build it Now™ Green FPS™ e-Series™ POWEREDGE® SyncFET™ CorePLUS™ GTO™ Power-SPM™ The Power Franchise® PowerTrench® CROSSVOLT™ i-l o™ p wer CTI ™ IntelliMAX™ Programmable Active Droop™ TinyBoost™ ISOPLANAR™ QFET[®] Current Transfer Logic™ EcoSPARK® MegaBuck™ QS™ TinyBuck™ TinyLogic[®] **F**[®] Fairchild[®] MICROCOUPLER™ QT Optoelectronics™ MicroFET™ Quiet Series™ TINYOPTO™ Fairchild Semiconductor® MicroPak™ RapidConfigure™ TinyPower™ TinyPWM™ Motion-SPM™ FACT Quiet Series™ SMART START™ OPTOLOGIC® SPM[®] TinyWire™ FACT[®] $\mathsf{FAST}^{\mathbb{R}}$ OPTOPLANAR® STEALTH™ µSerDes™ UHC® FastvCore[™] SuperFET™ SuperSOT™-3 PDP-SPM™ UniFET™ **FPS™** FRFET® Power220® SuperSOT™-6 VCX™ Global Power ResourceSM

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

Rev. I30

© 2007 Fairchild Semiconductor Corporation

www.fairchildsemi.com